

DATA SHEET

BIPOLAR ANALOG INTEGRATED CIRCUIT

μ**ΡC667**

10-BIT D/A CONVERTER

The μ PC667 is high-speed and high-precision 10-bit D/A converter. Clock rate of the μ PC667 is 60 Msps. Conversion precision of the μ PC667 is ±1.0 LSB.

FEATURES

- Resolution 10-bit
- Clock rate 60 Msps
- Technology Bi-CMOS
- Power supply +5 V
- D/A conversion method
- R-2R ladder resistance and segment summing system Voltage output type
- Analog output form Voltage ouBuilt-in reference voltage generating circuit

ORDERING INFORMATION

Part Number

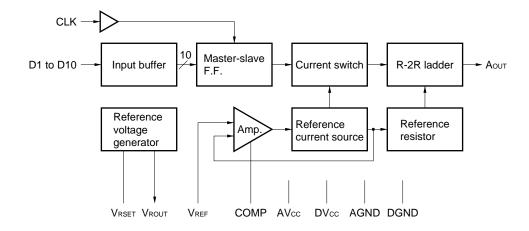
Package

μPC667CT

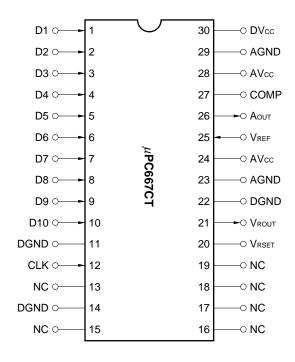
30-pin plastic shrink DIP (400 mil)

The information in this document is subject to change without notice.

BLOCK DIAGRAM



PIN CONFIGURATION (Top View)



AGND	:	Ground for Analog Circuit	
Aout	:	Analog Output	
AVcc	:	Power Supply for Analog Circuit	
CLK	:	Clock	
COMP	:	Phase Compensation	
D1 to D10):	Digital Signal	
DGND	:	Ground for Digital Circuit	
DVcc	:	Power Supply for Digital Circuit	
NC	:	No Connection	
Vref	:	Reference Voltage	
Vrout	:	Reference Voltage Output	
Vrset	:	Reference Voltage Adjustment	

PIN FUNCTIONS

Pin Name	Pin No.	Input/ Output	Function	Equivalent Circuit
D1 to D10	1 to 10	Input	Digital signal D1 is MSB, D10 is LSB.	DVcc DVcc 500 Ω JGND JGND DVcc T DVcc T DVcc T DVcc T DVcc T DVcc T DVcc T DVcc DVcc T DVcc T DVcc
CLK	12	Input	Clock The rising edge of signal input to this pin triggers analog output.	DVcc DVcc 500 Ω GND T DGND T DGND DVcc T DVcc T DVcc T DVcc DVcc T DVcc T DVcc DVcc T DVcc T DVcc
DVcc	30	_	Power supply for digital circuit	O DVcc
DGND	11, 14, 22	-	Ground for digital circuit	
Vrset	20	-	Reference voltage adjustment Voltage adjusting pin for the incorporated reference voltage generating circuit. The output voltage of V _{ROUT} pin varies according to the voltage applied to this pin. When no adjustment is necessary, connect approx. 0.1 μ F capacitance between this pin and GND pin.	AVcc AVcc $7.5 k\Omega$ AVcc V_{ROUT} $3 k\Omega$ $2 k\Omega$ V_{RSET} AGND
Vrout	21	Output	Reference voltage output Voltage output pin of the incorpo- rated reference voltage generating circuit. This pin has high output impedance, and must be connected with a high impedance element.	Reference 777 AGND voltage generator

Pin Name	Pin No.	Input/ Output	Function	Equivalent Circuit
Vref	25	Input	Reference voltage The output full-scale range is set according to the voltage applied to this pin. Apply standard 4.0 V. When no adjustment is necessary, connect the output from V _{ROUT} pin directly to this pin.	$ \begin{array}{c} $
Аоит	26	Output	Analog signal Analog signal output pin.	$\begin{array}{c} AV_{CC} \\ AV_{CC} \\ \hline \\ 112.5 \Omega \\ \hline \\ R-2R \\ Ladder \\ resistance \\ \hline \\ AGND \\ \hline \\ AGND \\ AGND \\ AGND \\ AGND \\ AGND \\ AGND \\ \hline \\ \\ AGND \\ \hline \\ \\ AGND \\ \hline \\ \\ \hline \\ \\ \hline \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ $
COMP	27	_	Phase compensation Phase compensating capacitor connection pin for full-scale ampli- fier. Approx. 0.1 μ F capacitor must be connected between this pin and AVcc pin.	AVcc AVcc AVcc \$9.7 kΩ \$9.7 kΩ AVcc AVcc AVcc AVcc COMP AGND AGND
AVcc	24, 28	_	Power supply for analog circuit	AVcc
AGND	23, 29	—	Ground for analog circuit	AGND
NC	13, 15 to 19	_	No Connection	0

ELECTRICAL SPECIFICATIONS

Absolute Maximum Ratings ($T_A = 25$ °C)

Parameter	Symbol	Ratings	Unit
Supply voltage for digital circuit	DVcc	-0.3 to +6.0	V
Input voltage	Vi	-0.3 to Vcc +0.3	V
Operating ambient temperature	TA	-20 to +70	°C
Storage temperature	Tstg	-40 to +125	°C
Power dissipation	Po	0.8 (T _A = +60 °C)	W
Supply voltage for analog circuit	AVcc	DVcc -0.3 to DVcc +0.3	V

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Caution Exposure to Absolute Maximum Rating for extended periods may affect device reliability; exceeding the ratings could cause permanent damage. The parameters apply independently.

Recommended Operating Conditions

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Supply voltage for digital circuit	DVcc		4.75	5.0	5.25	V
Supply voltage for analog circuit	AVcc		4.75	5.0	5.25	V
Reference voltage input pin voltage	Vref		3.8	4.0	4.2	V
High-level voltage of digital input	Vін		2.0			V
Low-level voltage of digital input	Vil				0.8	V
Conversion clock frequency	fськ				60	MHz
Phase compensation capacitance	Ссомр			1.0		μF

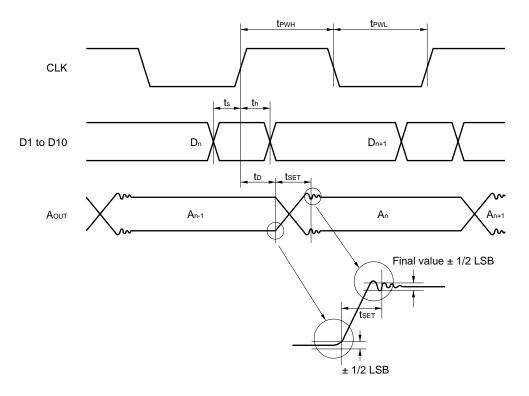
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Resolution	RSL			10		Bit
Integral linearity error	ILE	$T_A = 0 \text{ to } 60 \text{ °C}, V_{REF} = 4.0 \text{ V}$	-1.0		+1.0	LSB
Differential linearity error	DLE	$T_A = 0 \text{ to } 60 \text{ °C}, V_{REF} = 4.0 \text{ V}$	-1.0		+1.0	LSB
Supply current	lcc			50	71	mA
Set-up time	ts			3	7	ns
Hold time	th			1.5	7	ns
Settling time	t SET	$T_{\text{A}} = 25 \text{ °C}, \text{R}_{\text{L}} = 375 \Omega, \text{V}_{\text{REF}} = 4.0 \text{V}$		13		ns
Output delay time	td	Vref = 4.0 V		9	13	ns
Full-scale voltage output	Vofs	V_{REF} = 4.0 V, R_L > 100 k Ω	4.95		5.0	V
Zero-scale voltage output	Vozs	$V_{REF} = 4.0 \text{ V}, \text{ RL} > 100 \text{ k}\Omega$	3.95	4	4.05	V
Output resistance	Zout	Vref = 4.0 V	70	85	100	Ω
Internal reference voltage output voltage	Vrout	AVcc = 5.0 V	3.8	4.0	4.2	V

DC Characteristics and AC Characteristics (TA = -10 to +70 °C, DVcc = AVcc = +5 \pm 0.25 V)

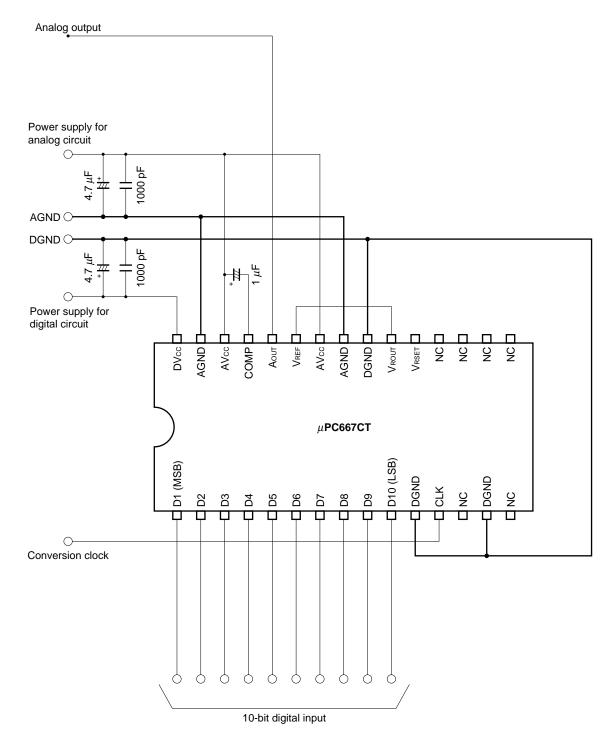
- Cautions 1. As for the phase compensation capacitance, capacitor of 1 μ F should be connected between the phase compensation capacitance pin (COMP) and the power supply pin for analog circuit (AVcc).
 - 2. The internal reference voltage output pin (VROUT) and the reference voltage input pin (VREF) should be shorted.
 - 3. The power supply and GND lines for analog circuit (AVcc and AGND) and those for digital circuit (DVcc and DGND) should be located as separately as possible.

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★ Timing Chart

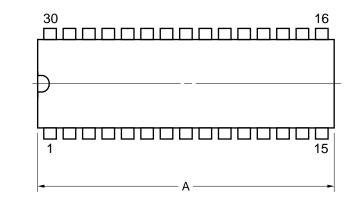


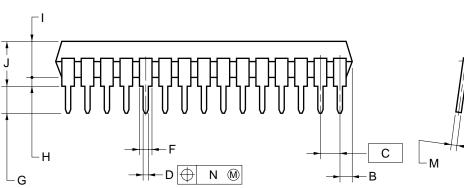
APPLICATION CIRCUIT EXAMPLE

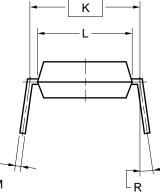


PACKAGE DRAWING

30PIN PLASTIC SHRINK DIP (400 mil)







NOTES

- 1) Each lead centerline is located within 0.17 mm (0.007 inch) of its true position (T.P.) at maximum material condition.
- 2) Item "K" to center of leads when formed parallel.

ITEM	MILLIMETERS	INCHES
А	28.46 MAX.	1.121 MAX.
В	1.78 MAX.	0.070 MAX.
С	1.778 (T.P.)	0.070 (T.P.)
D	0.50±0.10	$0.020^{+0.004}_{-0.005}$
F	0.85 MIN.	0.033 MIN.
G	3.2±0.3	0.126±0.012
Н	0.51 MIN.	0.020 MIN.
Ι	4.31 MAX.	0.170 MAX.
J	5.08 MAX.	0.200 MAX.
К	10.16 (T.P.)	0.400 (T.P.)
L	8.6	0.339
М	$0.25^{+0.10}_{-0.05}$	$0.010^{+0.004}_{-0.003}$
Ν	0.17	0.007
R	0~15°	0~15°
		S30C-70-400B-1

RECOMMENDED SOLDERING CONDITIONS

When soldering this product, it is highly recommended to observe the conditions as shown below. If other soldering processes are used, or if the soldering is performed under different conditions, please make sure to consult with our sales offices.

For more details, refer to our document "SEMICONDUCTOR DEVICE MOUNTING TECHNOLOGY MANUAL" (IEI-1207).

Through-hole device

μ PC667CT: 30-pin plastic Shrink DIP (400 mil)

Process	Conditions
Wave soldering (only to leads)	Solder temperature: 260 °C or below, Flow time: 10 seconds or less.
Partial heating method	Terminal temperature: 300 °C or below, Heat time: 3 seconds or less (Per each lead).

Caution For through-hole devices, the wave soldering process must be applied only to leads, and make sure that the package body does not get jet soldered.

[MEMO]

The application circuits and their parameters are for references only and are not intended for use in actual design-in's.

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"Standard", "Special", and "Specific". The Specific quality grade applies only to devices developed based on a customer designated "quality assurance program" for a specific application. The recommended applications of a device depend on its quality grade, as indicated below. Customers must check the quality grade of each device before using it in a particular application.

Standard: Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots

Special: Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)

Specific: Aircrafts, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems or medical equipment for life support, etc.

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Anti-radioactive design is not implemented in this product.

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